

# NUP8020X6

## 5-Line Transient Voltage Suppressor Array

This 5-line voltage transient suppressor array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as cell phones, portables, computers, printers and other applications. This device features a monolithic common anode design which protects five independent lines in a single SOT-563 package.

### Features

- Protects up to 5 Lines in a Single SOT-563 Package
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model.
- Compliance with IEC 61000-4-2 (ESD) 15 kV (Air), 8 kV (Contact)
- This is a Pb-Free Device

### Applications

- Hand Held Portable Applications
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

### MAXIMUM RATINGS (T<sub>J</sub> = 25°C, unless otherwise specified)

Symbol	Rating	Value	Unit
P <sub>PK</sub> 1	Peak Power Dissipation 8x20 μsec double exponential waveform, (Note 1)	90	W
T <sub>J</sub>	Operating Junction Temperature Range	-40 to 125	°C
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	°C
T <sub>L</sub>	Lead Solder Temperature – Maximum (10 seconds)	260	°C
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	16000 400 15000 8000	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Non-repetitive current pulse per Figure 1.

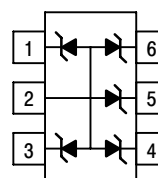


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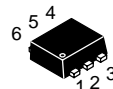
## SOT-563 5-LINE TRANSIENT VOLTAGE SUPPRESSOR

### PIN ASSIGNMENT

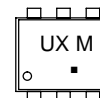


- PIN 1. CATHODE  
2. ANODE  
3. CATHODE  
4. CATHODE  
5. CATHODE  
6. CATHODE

### MARKING DIAGRAM



SOT-563  
CASE 463A  
STYLE 6



- UX = Specific Device Code  
M = Month Code  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

Device	Package	Shipping†
NUP8020X6T1G	SOT-563 (Pb-Free)	4000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

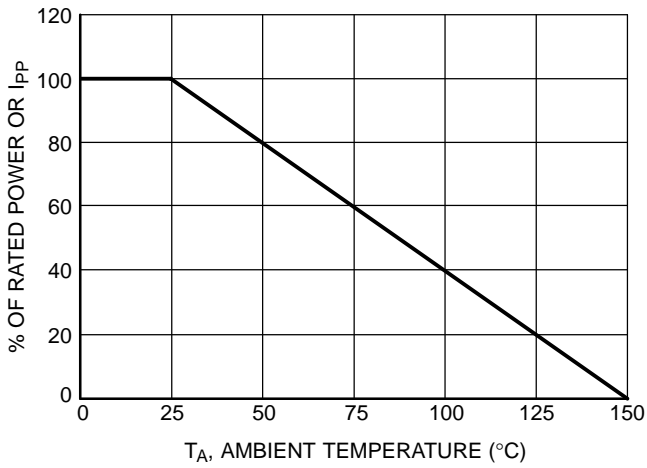
## NUP8020X6

### ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

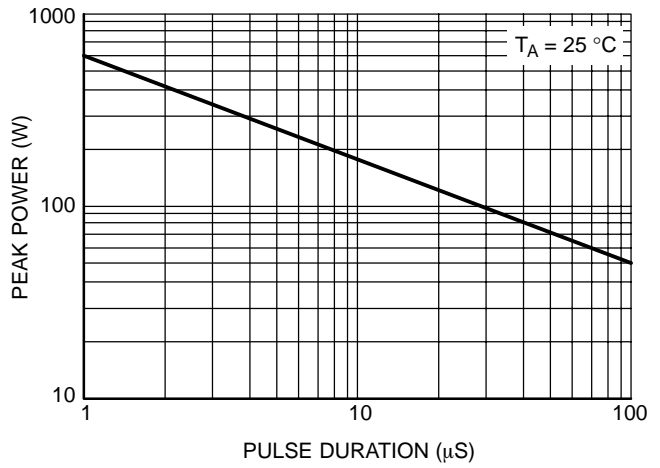
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Reverse Working Voltage	(Note 2)	$V_{RWM}$		–	5.0	V
Breakdown Voltage	$I_T = 1\text{ mA}$ , (Note 3)	$V_{BR}$	6.2	6.8	7.2	V
Reverse Leakage Current	$V_{RWM} = 3\text{ V}$	$I_R$	–	0.01	0.5	$\mu\text{A}$
Capacitance	$V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ (Line to GND) $V_R = 2.5\text{ V}$ , $f = 1\text{ MHz}$ (Line to GND)	$C_J$	–	54	70	pF

2. TVS devices are normally selected according to the working peak reverse voltage ( $V_{RWM}$ ), which should be equal or greater than the DC or continuous peak operating voltage level.
3.  $V_{BR}$  is measured at pulse test current  $I_T$ .

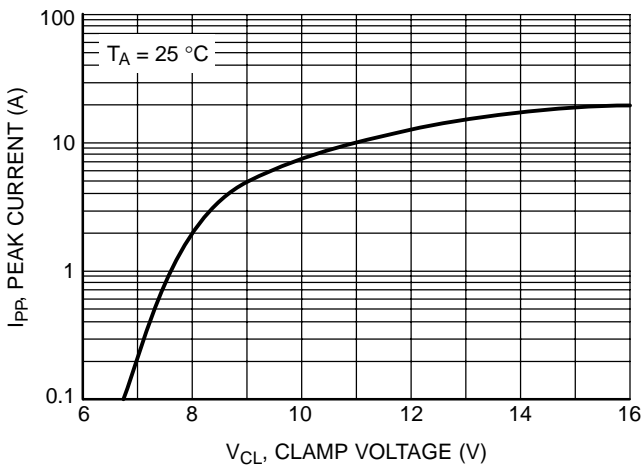
# NUP8020X6



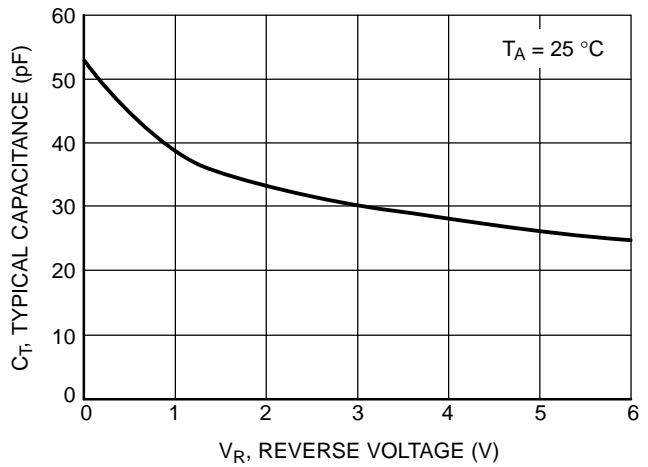
**Figure 1. Power Derating vs. Ambient Temperature**



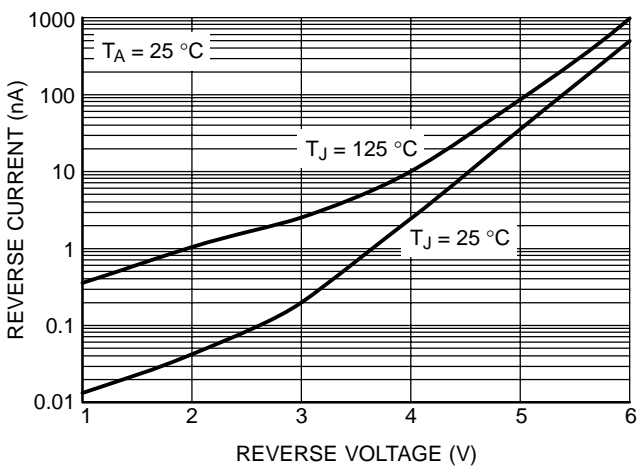
**Figure 2. Peak Power vs. Pulse Duration**



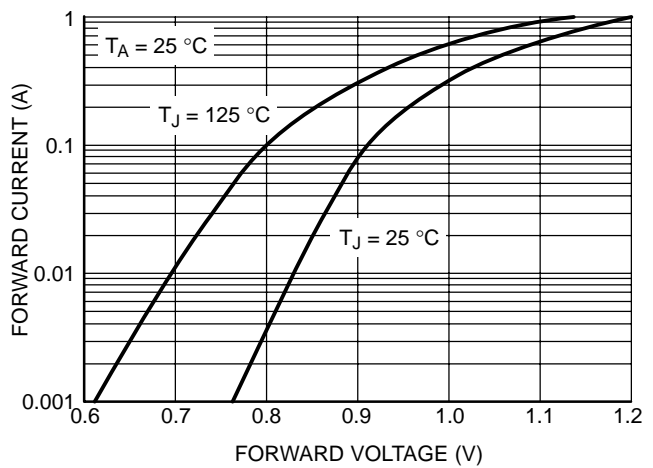
**Figure 3. Peak Current vs. Clamp Voltage**



**Figure 4. Typical Capacitance vs. Reverse Voltage**



**Figure 5. Reverse Current vs. Reverse Voltage**

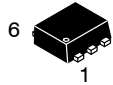


**Figure 6. Typical Forward Current vs. Forward Voltage**

# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

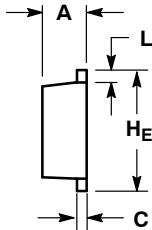
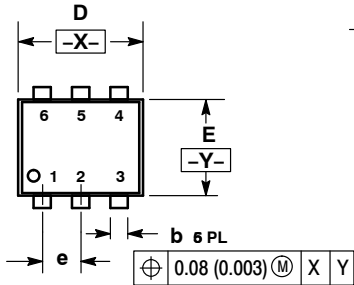
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SCALE 4:1

### SOT-563, 6 LEAD CASE 463A ISSUE G

DATE 23 SEP 2015

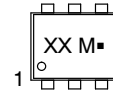


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.50	0.55	0.60	0.020	0.021	0.023
b	0.17	0.22	0.27	0.007	0.009	0.011
C	0.08	0.12	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.062	0.066
E	1.10	1.20	1.30	0.043	0.047	0.051
e	0.5 BSC			0.02 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
H <sub>E</sub>	1.50	1.60	1.70	0.059	0.062	0.066

### GENERIC MARKING DIAGRAM\*

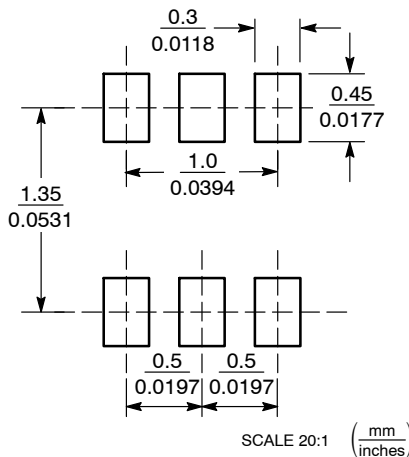


XX = Specific Device Code  
M = Month Code  
■ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present.

- |   |   |   |
|---|---|---|
| <p>STYLE 1:<br/>PIN 1. EMITTER 1<br/>2. BASE 1<br/>3. COLLECTOR 2<br/>4. EMITTER 2<br/>5. BASE 2<br/>6. COLLECTOR 1</p> | <p>STYLE 2:<br/>PIN 1. EMITTER 1<br/>2. EMITTER 2<br/>3. BASE 2<br/>4. COLLECTOR 2<br/>5. BASE 1<br/>6. COLLECTOR 1</p> | <p>STYLE 3:<br/>PIN 1. CATHODE 1<br/>2. CATHODE 1<br/>3. ANODE/ANODE 2<br/>4. CATHODE 2<br/>5. CATHODE 2<br/>6. ANODE/ANODE 1</p> |
| <p>STYLE 4:<br/>PIN 1. COLLECTOR<br/>2. COLLECTOR<br/>3. BASE<br/>4. EMITTER<br/>5. COLLECTOR<br/>6. COLLECTOR</p>      | <p>STYLE 5:<br/>PIN 1. CATHODE<br/>2. CATHODE<br/>3. ANODE<br/>4. ANODE<br/>5. CATHODE<br/>6. CATHODE</p>               | <p>STYLE 6:<br/>PIN 1. CATHODE<br/>2. ANODE<br/>3. CATHODE<br/>4. CATHODE<br/>5. CATHODE<br/>6. CATHODE</p>                       |
| <p>STYLE 7:<br/>PIN 1. CATHODE<br/>2. ANODE<br/>3. CATHODE<br/>4. CATHODE<br/>5. ANODE<br/>6. CATHODE</p>               | <p>STYLE 8:<br/>PIN 1. DRAIN<br/>2. DRAIN<br/>3. GATE<br/>4. SOURCE<br/>5. DRAIN<br/>6. DRAIN</p>                       | <p>STYLE 9:<br/>PIN 1. SOURCE 1<br/>2. GATE 1<br/>3. DRAIN 2<br/>4. SOURCE 2<br/>5. GATE 2<br/>6. DRAIN 1</p>                     |
| <p>STYLE 10:<br/>PIN 1. CATHODE 1<br/>2. N/C<br/>3. CATHODE 2<br/>4. ANODE 2<br/>5. N/C<br/>6. ANODE 1</p>              |   |   |

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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